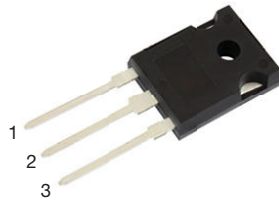
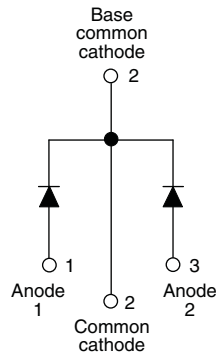


Ultrafast Soft Recovery Diode, 2 x 30 A FRED Pt® Gen 4



TO-247AD 3L



FEATURES

- Gen 4 FRED Pt® technology
- Low I_{RRM} and reverse recovery charge
- Very low forward voltage drop
- Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 30 A
V_R	600 V
V_F at I_F	1.19 V
t_r typ.	See Recovery table
T_J max.	175 °C
Package	TO-247AD 3L
Circuit configuration	Common cathode

DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V_F , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode. The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 131$ °C	30	A
Non-repetitive peak surge current, per leg	I_{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave	240	
Operating junction and storage temperature	T_J, T_{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100$ μ A	600	-	-	V
Forward voltage	V_F	$I_F = 30$ A	-	1.36	1.6	
		$I_F = 60$ A	-	1.6	-	
		$I_F = 30$ A, $T_J = 125$ °C	-	1.23	-	
		$I_F = 60$ A, $T_J = 125$ °C	-	1.5	-	
		$I_F = 30$ A, $T_J = 150$ °C	-	1.19	1.35	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	-	50	μ A
		$T_J = 125$ °C, $V_R = V_R$ rated	-	-	500	
Junction capacitance	C_T	$V_R = 600$ V	-	18.3	-	pF



DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 30\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	65	-	ns
		$T_J = 125\text{ }^\circ\text{C}$		-	90	-	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^\circ\text{C}$		-	18	-	A
		$T_J = 125\text{ }^\circ\text{C}$		-	32	-	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^\circ\text{C}$		-	850	-	nC
		$T_J = 125\text{ }^\circ\text{C}$		-	1850	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R_{thJC}			-	-	1	$^\circ\text{C}/\text{W}$
Thermal resistance, case to heat sink	R_{thCS}			-	0.4	-	
Weight				-	6.0	-	g
				-	0.21	-	oz.
Mounting torque				6.0 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AD 3L		C4PU3006LH			

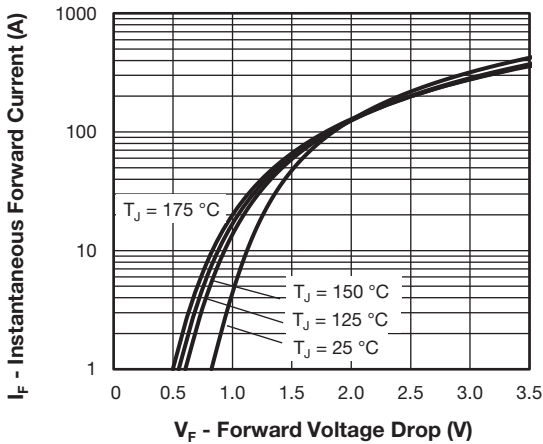


Fig. 1 - Typical Forward Voltage Drop Characteristics

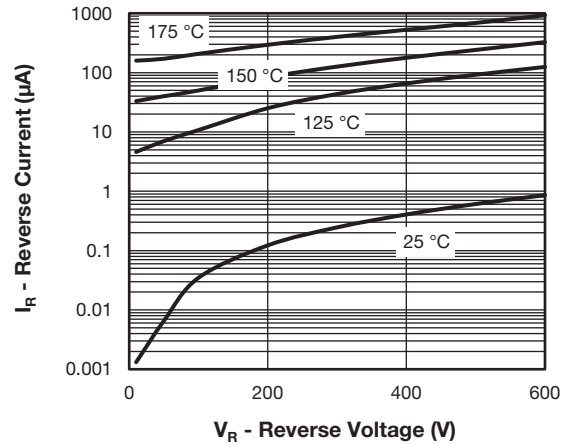


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

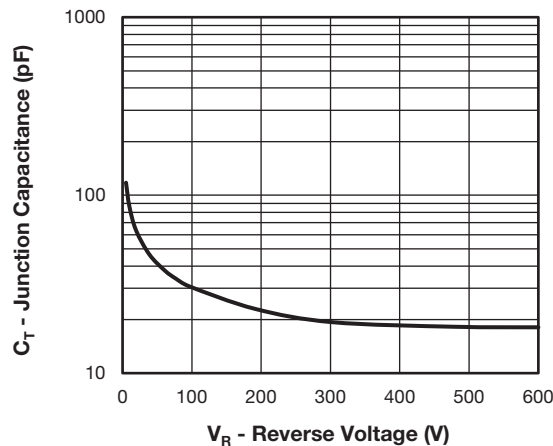


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

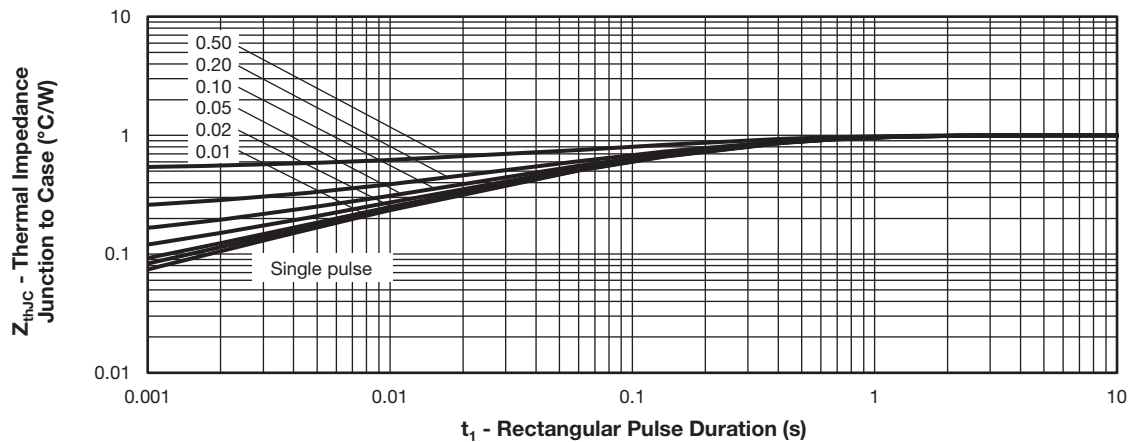


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

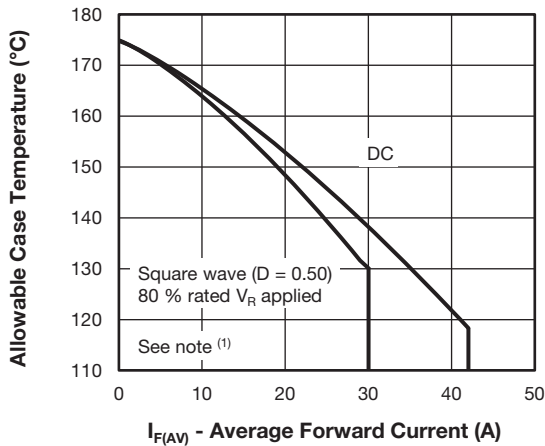


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

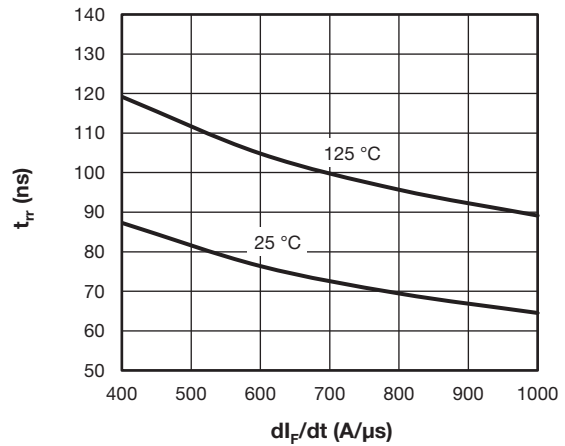


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

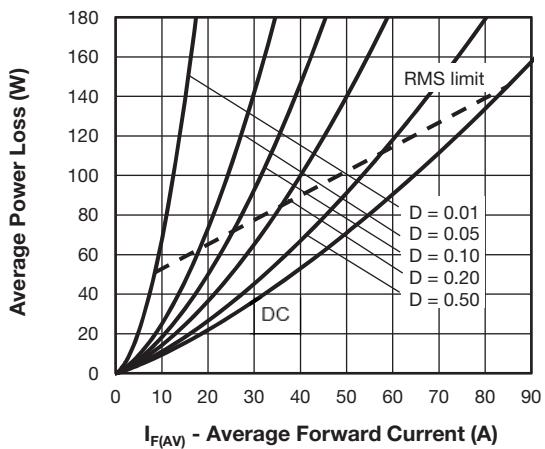


Fig. 6 - Forward Power Loss Characteristics

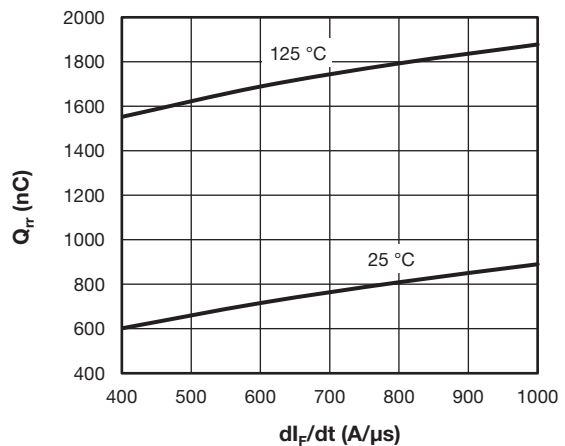


Fig. 8 - Typical Stored Charge vs. dI_F/dt

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see Fig.5)
 P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_R = rated V_R

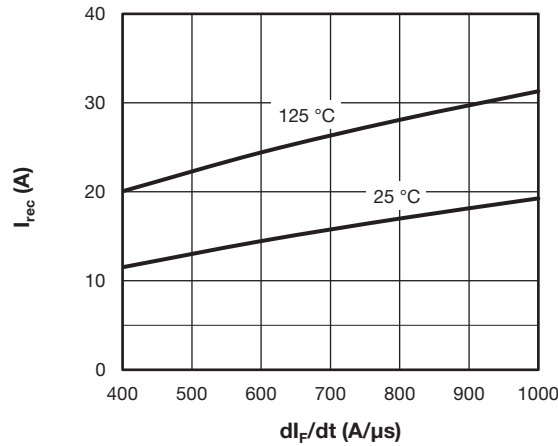


Fig. 9 - Typical Reverse Current vs. di/dt

ORDERING INFORMATION TABLE

Device code	VS-	C	4	P	U	60	06	L	H	N3
	①	②	③	④	⑤	⑥	⑦	⑧	⑨	⑩
	1	- Vishay Semiconductors product								
	2	- Circuit configuration: C = common diode								
	3	- FRED Pt Gen 4								
	4	- P = TO-247 package								
	5	- Process type: U = ultrafast recovery								
	6	- Current rating (60 = 2 x 30 A)								
	7	- Voltage rating (06 = 600 V)								
	8	- Package: L = long lead								
	9	- H = AEC-Q101 qualified								
	10	- Environmental digit: N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free								

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-C4PU6006LHN3	25	500	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007



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